## NSN 5961-01-122-7608



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-122-7608 **Inclosure Material:** Metal **Overall Length:** 0.625 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **End Application:** Hull obrp **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 80.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 60.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

## **NSN 5961-01-122-7608** Transistor - Page 2 of 2



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